

**For Scintillation Counting, Photon Counting,
Ruggedized, Low Profile, 25 mm (1 Inch) Diameter,
Bialkali Photocathode, 10-stage, Head-on Type**

GENERAL

Parameter		Description	Unit
Spectral Response		300 to 650	nm
Peak Wavelength		420	nm
Photocathode	Material	Bialkali	—
	Minimum Effective Area	22	mm dia.
Window Material		Borosilicate glass	—
Dynode	Structure	Linear focused	—
	Number of Stages	10	—
Base		14 pin glass base	—
Suitable Socket		E678-14C (supplied)	—
Operating Ambient Temperature		-30 to +50	°C
Storage Temperature		-80 to +50	°C

MAXIMUM RATINGS (Absolute Maximum Values)

Parameter		Value	Unit
Supply Voltage	Between Anode and Cathode	1250	V
	Between Anode and Last Dynode	250	V
Average Anode Current		0.1	mA

CHARACTERISTICS (at 25 °C) with Standard Voltage Divider

Parameter		Min.	Typ.	Max.	Unit
Cathode Sensitivity	Luminous (2856 K)	60	90	—	μA/lm
	Quantum Efficiency at 420 nm	—	26	—	%
	Blue Sensitivity index (CS 5-58)	9	10.5	—	—
Anode Sensitivity	Luminous (2856 K)	40	180	—	A/lm
Gain		—	2.0×10^6	—	—
Anode Dark Current (after 30 min storage in darkness)		—	3	20	nA
Time Response	Anode Pulse Rise Time	—	1.5	—	ns
	Electron Transit Time	—	17	—	ns
	Transit Time Spread (TTS)	—	0.9	—	ns
Pulse Linearity at ±2 % deviation		—	30	—	mA

NOTE: Anode characteristics are measured with a voltage distribution ratio shown below

STANDARD VOLTAGE DIVIDER AND SUPPLY VOLTAGE

Electrodes	K	Dy1	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	P
Ratio	3	1	1	1	1	1	1	1	1	1	1	1

Supply Voltage: 1000 V, K: Cathode, Dy: Dynode, P: Anode

ENVIRONMENTAL TESTING

Shock.....1000 m/s², 11 ms, 3 impact shocks per direction (6 directions)

Vibration.....200 m/s², 50 Hz to 2000 Hz, 1 oct per minute, 3 sweeps per axis (3 axes)

PHOTOMULTIPLIER TUBE R1924A

Figure 1: Typical Spectral Response

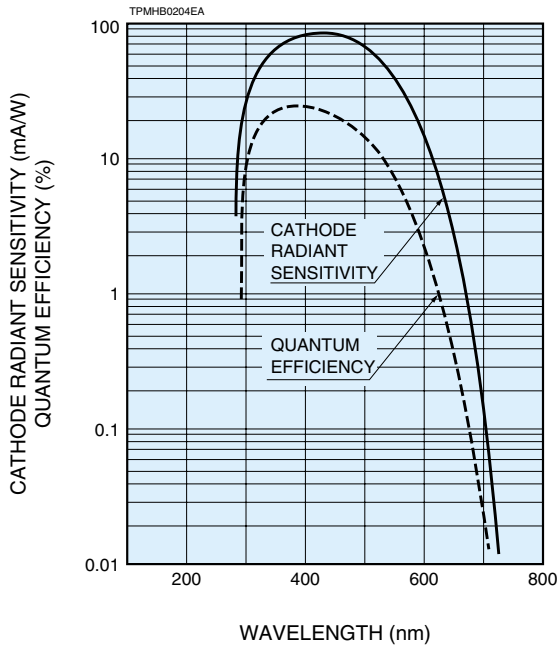


Figure 2: Typical Gain and Dark Current Characteristics

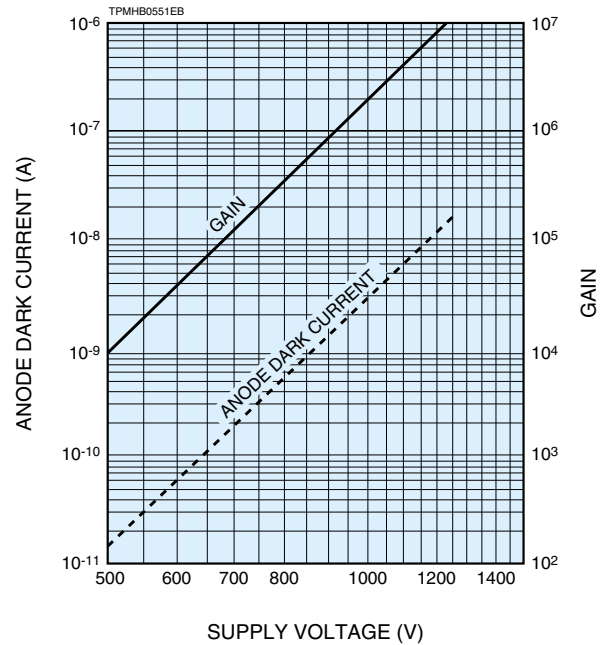
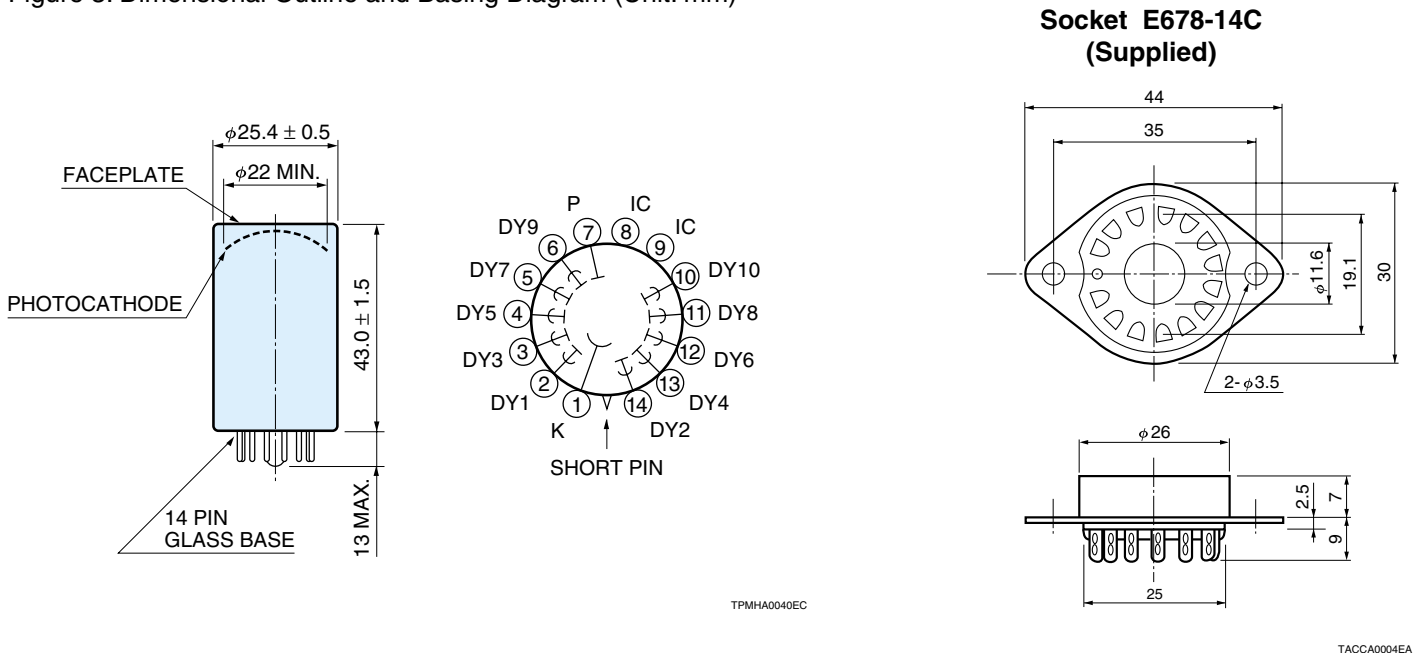


Figure 3: Dimensional Outline and Basing Diagram (Unit: mm)



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